



SCCS064B - August 1994 - Revised September 2001

# CY74FCT16827T CY74FCT162827T

## 20-Bit Buffers/Line Drivers

### Features

- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Edge-rate control circuitry for significantly improved noise characteristics
- Typical output skew < 250 ps
- ESD > 2000V
- TSSOP (19.6-mil pitch) and SSOP (25-mil pitch) packages
- Industrial temperature range of  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$
- $V_{CC} = 5\text{V} \pm 10\%$

#### CY74FCT16827T Features:

- 64 mA sink current, 32 mA source current
- Typical  $V_{OLP}$  (ground bounce) < 1.0V at  $V_{CC} = 5\text{V}$ ,  $T_A = 25^{\circ}\text{C}$

#### CY74FCT162827T Features:

- Balanced 24 mA output drivers
- Reduced system switching noise
- Typical  $V_{OLP}$  (ground bounce) < 0.6V at  $V_{CC} = 5\text{V}$ ,  $T_A = 25^{\circ}\text{C}$

### Functional Description

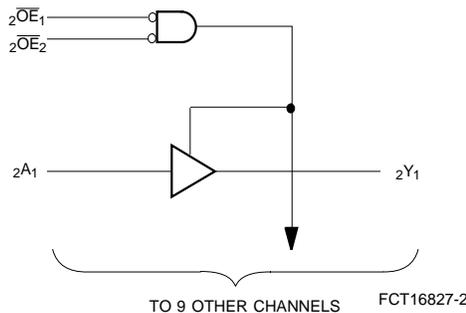
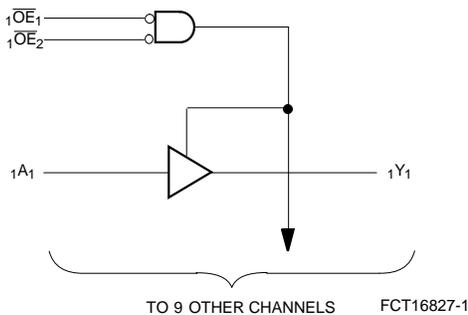
The CY74FCT16827T 20-bit buffer/line driver and the CY74FCT162827T 20-bit buffer/line driver provide high-performance bus interface buffering for wide data/address paths or buses carrying parity. These parts can be used as a single 20-bit buffer or two 10-bit buffers. Each 10-bit buffer has a pair of NANDed OE for increased flexibility.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The CY74FCT16827T is ideally suited for driving high-capacitance loads and low-impedance backplanes.

The CY74FCT162827T has 24-mA balanced output drivers with current-limiting resistors in the outputs. This reduces the need for external terminating resistors and provides for minimal undershoot and reduced ground bounce. The CY74FCT162827T is ideal for driving transmission lines.

### Logic Block Diagrams



### Pin Configuration

**SSOP/TSSOP  
Top View**

$\overline{1OE_1}$	1	56	$\overline{1OE_2}$
$1Y_1$	2	55	$1A_1$
$1Y_2$	3	54	$1A_2$
GND	4	53	GND
$1Y_3$	5	52	$1A_3$
$1Y_4$	6	51	$1A_4$
$V_{CC}$	7	50	$V_{CC}$
$1Y_5$	8	49	$1A_5$
$1Y_6$	9	48	$1A_6$
$1Y_7$	10	47	$1A_7$
GND	11	46	GND
$1Y_8$	12	45	$1A_8$
$1Y_9$	13	44	$1A_9$
$1Y_{10}$	14	43	$1A_{10}$
$2Y_1$	15	42	$2A_1$
$2Y_2$	16	41	$2A_2$
$2Y_3$	17	40	$2A_3$
GND	18	39	GND
$2Y_4$	19	38	$2A_4$
$2Y_5$	20	37	$2A_5$
$V_{CC}$	22	35	$V_{CC}$
$2Y_7$	23	34	$2A_7$
$2Y_8$	24	33	$2A_8$
GND	25	32	GND
$2Y_9$	26	31	$2A_9$
$2Y_{10}$	27	30	$2A_{10}$
$\overline{2OE_1}$	28	29	$\overline{2OE_2}$

FCT16827-3

**Pin Description**

Name	Description
$\overline{OE}$	Output Enable Inputs (Active LOW)
A	Data Inputs
Y	Three-State Outputs

**Function Table<sup>[1]</sup>**

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	A	Y
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

**Maximum Ratings<sup>[2, 3]</sup>**

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature.....	-55°C to +125°C
Ambient Temperature with Power Applied.....	-55°C to +125°C
DC Input Voltage .....	-0.5V to +7.0V
DC Output Voltage .....	-0.5V to +7.0V
DC Output Current (Maximum Sink Current/Pin) .....	-60 to +120 mA
Power Dissipation .....	1.0W
Static Discharge Voltage.....	>2001V (per MIL-STD-883, Method 3015)

**Operating Range**

Range	Ambient Temperature	V <sub>CC</sub>
Industrial	-40°C to +85°C	5V ± 10%

**Electrical Characteristics** Over the Operating Range

Parameter	Description	Test Conditions	Min.	Typ. <sup>[4]</sup>	Max.	Unit
V <sub>IH</sub>	Input HIGH Voltage		2.0			V
V <sub>IL</sub>	Input LOW Voltage				0.8	V
V <sub>H</sub>	Input Hysteresis <sup>[5]</sup>			100		mV
V <sub>IK</sub>	Input Clamp Diode Voltage	V <sub>CC</sub> =Min., I <sub>IN</sub> =-18 mA		-0.7	-1.2	V
I <sub>IH</sub>	Input HIGH Current	V <sub>CC</sub> =Max., V <sub>I</sub> =V <sub>CC</sub>			±1	µA
I <sub>IL</sub>	Input LOW Current	V <sub>CC</sub> =Max., V <sub>I</sub> =GND			±1	µA
I <sub>OZH</sub>	High Impedance Output Current (Three-State Output pins)	V <sub>CC</sub> =Max., V <sub>OUT</sub> =2.7V			±1	µA
I <sub>OZL</sub>	High Impedance Output Current (Three-State Output pins)	V <sub>CC</sub> =Max., V <sub>OUT</sub> =0.5V			±1	µA
I <sub>OS</sub>	Short Circuit Current <sup>[6]</sup>	V <sub>CC</sub> =Max., V <sub>OUT</sub> =GND	-80	-140	-200	mA
I <sub>O</sub>	Output Drive Current <sup>[6]</sup>	V <sub>CC</sub> =Max., V <sub>OUT</sub> =2.5V	-50		-180	mA
I <sub>OFF</sub>	Power-Off Disable	V <sub>CC</sub> =0V, V <sub>OUT</sub> ≤4.5V <sup>[7]</sup>			±1	µA

**Output Drive Characteristics for CY74FCT16827T**

Parameter	Description	Test Conditions	Min.	Typ. <sup>[4]</sup>	Max.	Unit
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> =Min., I <sub>OH</sub> =-3 mA	2.5	3.5		V
		V <sub>CC</sub> =Min., I <sub>OH</sub> =-15 mA	2.4	3.5		
		V <sub>CC</sub> =Min., I <sub>OH</sub> =-32 mA	2.0	3.0		
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> =Min., I <sub>OL</sub> =64 mA		0.2	0.55	V

- H = HIGH Voltage Level. L = LOW Voltage Level. X = Don't Care. Z = HIGH Impedance.
- Operation beyond the limits set forth may impair the useful life of the device. Unless noted, these limits are over the operating free-air temperature range.
- Unused inputs must always be connected to an appropriate logic voltage level, preferably either V<sub>CC</sub> or ground.
- Typical values are at V<sub>CC</sub>= 5.0V, T<sub>A</sub>= +25°C ambient.
- This parameter is specified but not tested.
- Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parametric tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.
- Tested at +25°C.

### Output Drive Characteristics for CY74FCT162827T

Parameter	Description	Test Conditions	Min.	Typ. <sup>[4]</sup>	Max.	Unit
I <sub>ODL</sub>	Output LOW Current <sup>[6]</sup>	V <sub>CC</sub> =5V, V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub> , V <sub>OUT</sub> =1.5V	60	115	150	mA
I <sub>ODH</sub>	Output HIGH Current <sup>[6]</sup>	V <sub>CC</sub> =5V, V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub> , V <sub>OUT</sub> =1.5V	-60	-115	-150	mA
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> =Min., I <sub>OH</sub> =-24 mA	2.4	3.3		V
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> =Min., I <sub>OL</sub> =24 mA		0.3	0.55	V

### Capacitance<sup>[5]</sup> (T<sub>A</sub> = +25°C, f = 1.0 MHz)

Parameter	Description	Test Conditions	Typ. <sup>[4]</sup>	Max.	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0V	4.5	6.0	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>OUT</sub> = 0V	5.5	8.0	pF

### Power Supply Characteristics

Parameter	Description	Test Conditions	Min.	Typ. <sup>[4]</sup>	Max.	Unit	
I <sub>CC</sub>	Quiescent Power Supply Current	V <sub>CC</sub> =Max. V <sub>IN</sub> ≤0.2V, V <sub>IN</sub> ≥V <sub>CC</sub> -0.2V	—	5	500	μA	
ΔI <sub>CC</sub>	Quiescent Power Supply Current (TTL inputs HIGH)	V <sub>CC</sub> =Max. V <sub>IN</sub> =3.4V <sup>[8]</sup>	—	0.5	1.5	mA	
I <sub>CCD</sub>	Dynamic Power Supply Current <sup>[9]</sup>	V <sub>CC</sub> =Max., One Input Toggling, 50% Duty Cycle, Outputs Open, OE <sub>1</sub> =OE <sub>2</sub> =GND,	—	60	100	μA/MHz	
I <sub>C</sub>	Total Power Supply Current <sup>[10]</sup>	V <sub>CC</sub> =Max., f <sub>1</sub> =10 MHz, 50% Duty Cycle, Outputs Open, One Bit Toggling, OE <sub>1</sub> =OE <sub>2</sub> =GND	V <sub>IN</sub> =V <sub>CC</sub> or V <sub>IN</sub> =GND	—	0.6	1.5	mA
		V <sub>IN</sub> =3.4V or V <sub>IN</sub> =GND	—	0.9	2.3		
		V <sub>CC</sub> =Max., f <sub>1</sub> =2.5 MHz, 50% Duty Cycle, Outputs Open, Twenty Bits Toggling, OE <sub>1</sub> =OE <sub>2</sub> =GND	V <sub>IN</sub> =V <sub>CC</sub> or V <sub>IN</sub> =GND	—	3.0	5.5 <sup>[11]</sup>	
			V <sub>IN</sub> =3.4V or V <sub>IN</sub> =GND	—	8.0	20.5 <sup>[11]</sup>	

#### Notes:

8. Per TTL driven input (V<sub>IN</sub>=3.4V); all other inputs at V<sub>CC</sub> or GND.
9. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
10.  $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$   
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_0/2 + f_1 N_1)$   
 $I_{CC}$  = Quiescent Current with CMOS input levels  
 $\Delta I_{CC}$  = Power Supply Current for a TTL HIGH input (V<sub>IN</sub>=3.4V)  
 $D_H$  = Duty Cycle for TTL inputs HIGH  
 $N_T$  = Number of TTL inputs at D<sub>H</sub>  
 $I_{CCD}$  = Dynamic Current caused by an input transition pair (HLH or LHL)  
 $f_0$  = Clock frequency for registered devices, otherwise zero  
 $f_1$  = Input signal frequency  
 $N_1$  = Number of inputs changing at f<sub>1</sub>  
 All currents are in milliamps and all frequencies are in megahertz.
11. Values for these conditions are examples of the I<sub>CC</sub> formula. These limits are specified but not tested.

**Switching Characteristics** Over the Operating Range<sup>[12]</sup>

Parameter	Description	Condition <sup>[13]</sup>	CY74FCT16827AT CY74FCT162827AT		CY74FCT162827BT		Unit	Fig. No. <sup>[13]</sup>
			Min.	Max.	Min.	Max.		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay A to Y	C <sub>L</sub> =50 pF R <sub>L</sub> =500Ω	1.5	8.0	1.5	5.0	ns	1, 3
		C <sub>L</sub> =300 pF R <sub>L</sub> =500Ω	1.5	15.0	1.5	13.0		
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time OE to Y	C <sub>L</sub> =50 pF R <sub>L</sub> =500Ω	1.5	12.0	1.5	8.0	ns	1, 7, 8
		C <sub>L</sub> =300 pF R <sub>L</sub> =500Ω	1.5	23.0	1.5	15.0		
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time OE to Y	C <sub>L</sub> =5 pF R <sub>L</sub> =500Ω	1.5	9.0	1.5	6.0	ns	1, 7, 8
		C <sub>L</sub> =50 pF R <sub>L</sub> =500Ω	1.5	10.0	1.5	7.0		
t <sub>SK(O)</sub>	Output Skew <sup>[14]</sup>		—	0.5	—	0.5	ns	—

Parameter	Description	Condition <sup>[12]</sup>	CY74FCT16827CT CY74FCT162827CT		Unit	Fig. No. <sup>[13]</sup>
			Min.	Max.		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay A to Y	C <sub>L</sub> =50 pF R <sub>L</sub> =500Ω	1.5	4.2	ns	1, 3
		C <sub>L</sub> =300 pF R <sub>L</sub> =500Ω	1.5	10.0		
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time OE to Y	C <sub>L</sub> =50 pF R <sub>L</sub> =500Ω	1.5	5.6	ns	1, 7, 8
		C <sub>L</sub> =300 pF R <sub>L</sub> =500Ω	1.5	14.0		
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time OE to Y	C <sub>L</sub> =5 pF R <sub>L</sub> =500Ω	1.5	5.7	ns	1, 7, 8
		C <sub>L</sub> =50 pF R <sub>L</sub> =500Ω	1.5	6.0		
t <sub>SK(O)</sub>	Output Skew <sup>[14]</sup>		—	0.5	ns	—

**Notes:**

12. Minimum limits are specified but not tested on Propagation Delays.
13. See "Parameter Measurement Information" in the General Information section.
14. Skew between any two outputs of the same package switching in the same direction. This parameter is ensured by design.

**Ordering Information CY74FCT16827**

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
4.2	CY74FCT16827CTPACT	Z56	56-Lead (240-Mil) TSSOP	Industrial
	CY74FCT16827CTPVC/PVCT	O56	56-Lead (300-Mil) SSOP	
8.0	CY74FCT16827ATPVC/PVCT	Z56	56-Lead (240-Mil) SSOP	Industrial

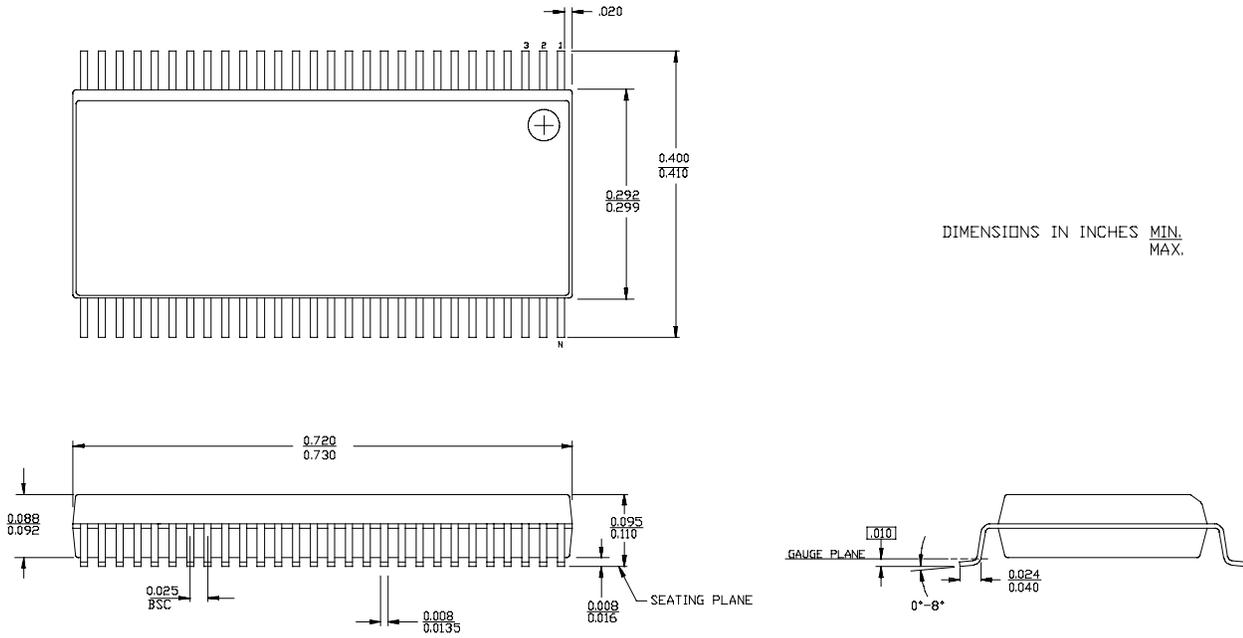
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**Ordering Information CY74FCT162827**

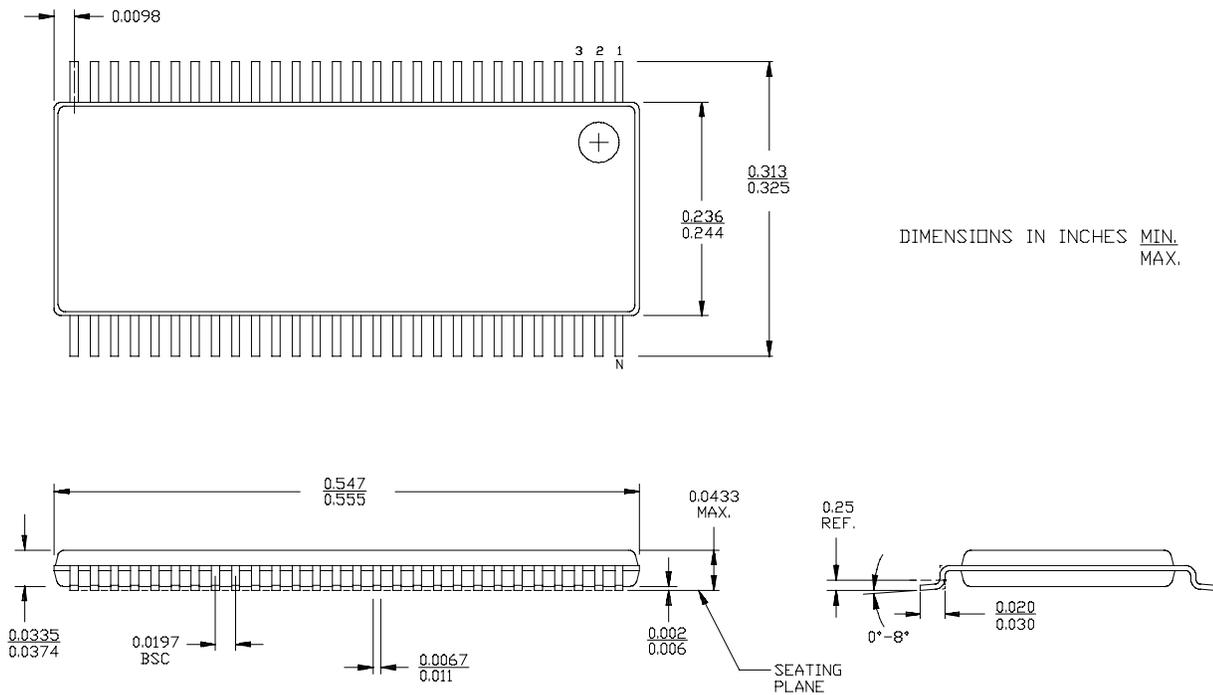
Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
4.2	74FCT162827CTPACT	Z56	56-Lead (240-Mil) TSSOP	Industrial
	CY74FCT162827CTPVC	Z56	56-Lead (240-Mil) SSOP	
	74FCT162827CTPVCT	Z56	56-Lead (240-Mil) SSOP	
5.0	CY74FCT162827BTPVC	O56	56-Lead (300-Mil) SSOP	Industrial
	74FCT162827BTPVCT	O56	56-Lead (300-Mil) SSOP	
8.0	CY74FCT162827ATPVC	O56	56-Lead (300-Mil) SSOP	Industrial
	74FCT162827ATPVCT	O56	56-Lead (300-Mil) SSOP	

**Package Diagrams**

**56-Lead Shrunken Small Outline Package O56**



**56-Lead Thin Shrunken Small Outline Package Z56**



**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
74FCT162827ATPACT	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT162827A	<a href="#">Samples</a>
74FCT162827CTPACT	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT162827C	<a href="#">Samples</a>
CY74FCT162827ATPVC	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT162827A	<a href="#">Samples</a>
CY74FCT16827ATPVC	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT16827A	<a href="#">Samples</a>
CY74FCT16827CTPACT	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT16827C	<a href="#">Samples</a>
CY74FCT16827CTPVC	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT16827C	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

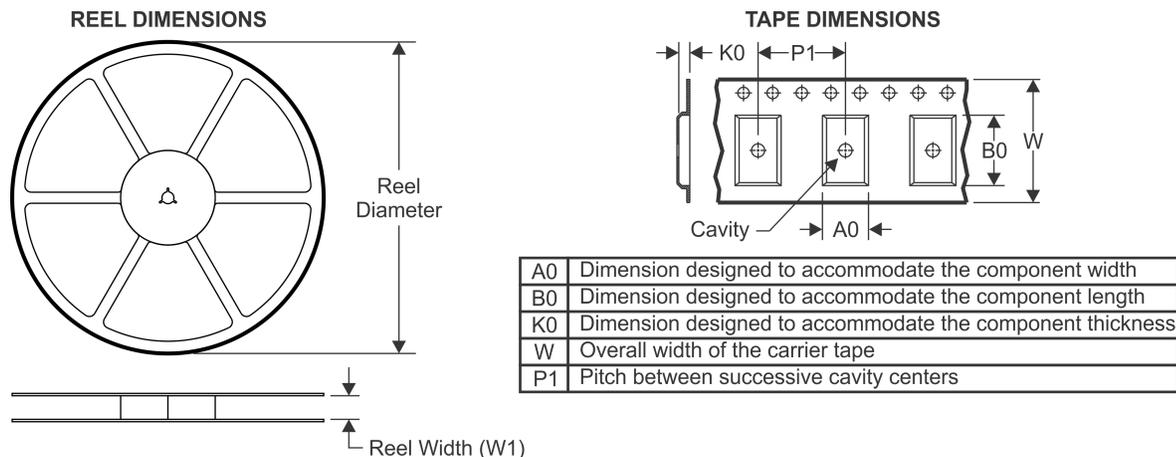
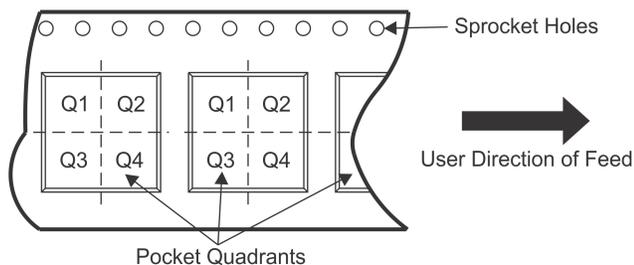
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

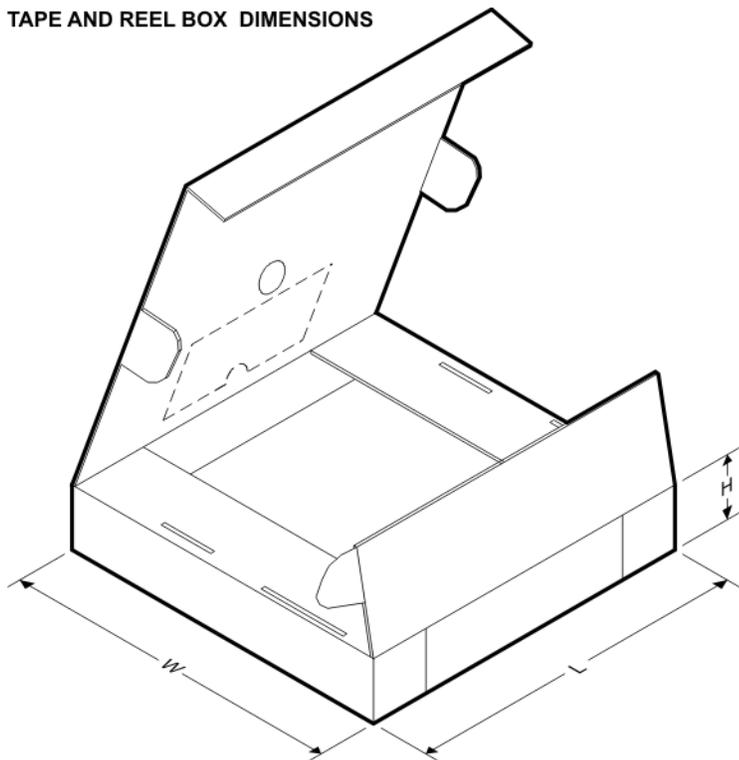
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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


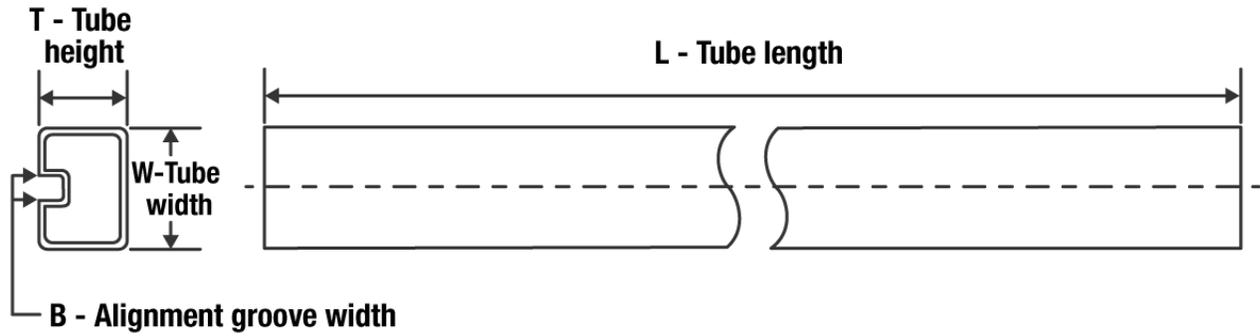
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74FCT162827ATPACT	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
74FCT162827CTPACT	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
CY74FCT16827CTPACT	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74FCT162827ATPACT	TSSOP	DGG	56	2000	367.0	367.0	45.0
74FCT162827CTPACT	TSSOP	DGG	56	2000	367.0	367.0	45.0
CY74FCT16827CTPACT	TSSOP	DGG	56	2000	367.0	367.0	45.0

**TUBE**


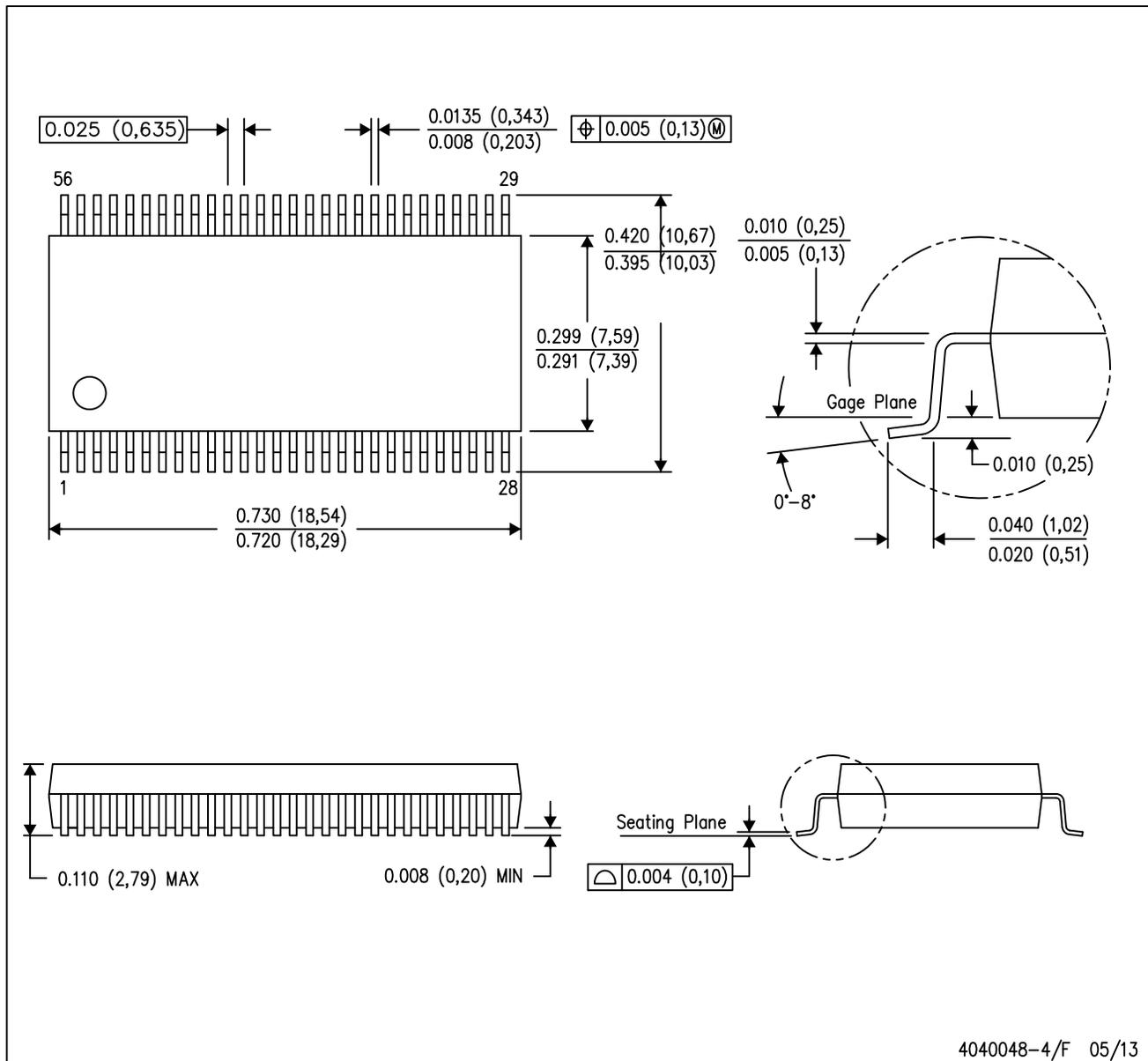
\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
CY74FCT162827ATPVC	DL	SSOP	56	20	473.7	14.24	5110	7.87
CY74FCT16827ATPVC	DL	SSOP	56	20	473.7	14.24	5110	7.87
CY74FCT16827CTPVC	DL	SSOP	56	20	473.7	14.24	5110	7.87

# MECHANICAL DATA

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.

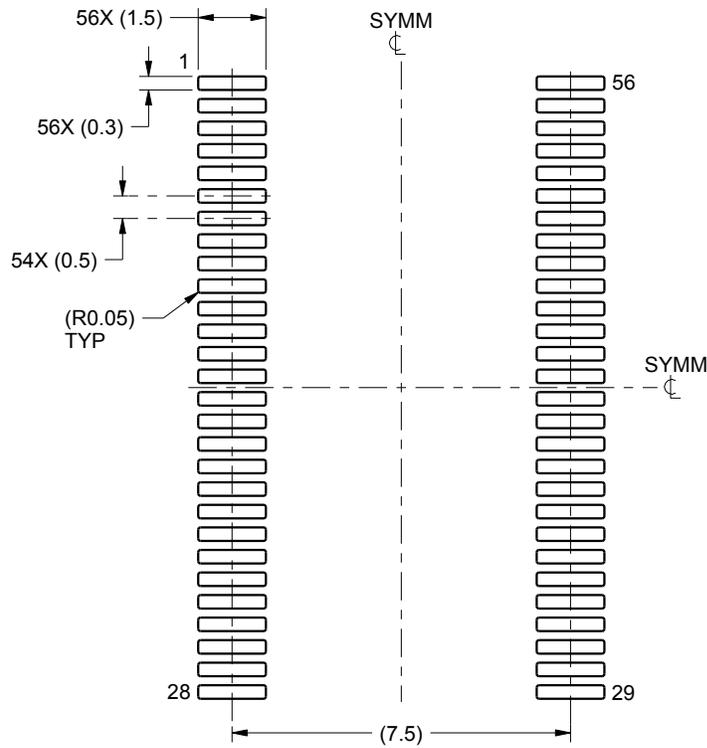


# EXAMPLE BOARD LAYOUT

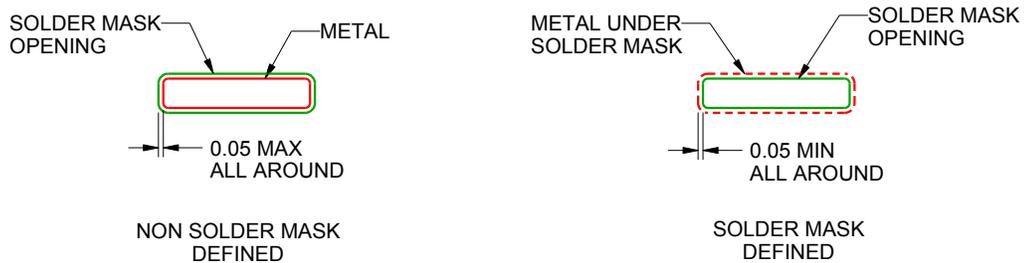
DGG0056A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:6X



SOLDER MASK DETAILS

4222167/A 07/2015

NOTES: (continued)

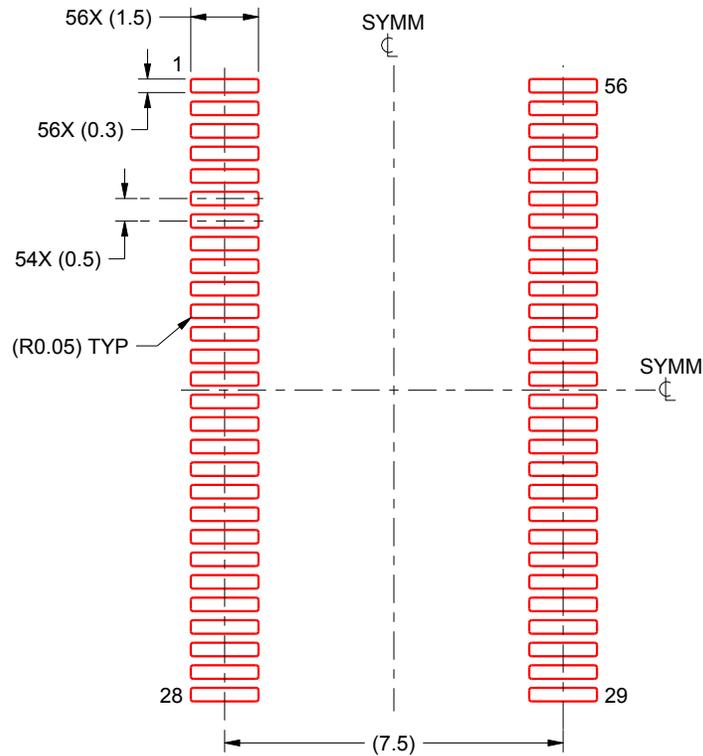
- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DGG0056A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:6X

4222167/A 07/2015

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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